# NSN 5961-00-484-7740

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## Inclosure Material:

Metal

# **Overall Length:**

Between 0.049 inches and 0.061 inches

# **Overall Diameter:**

Between 0.078 inches and 0.092 inches

# Internal Configuration:

Junction contact

#### **Mounting Method:**

Press fit

# **Features Provided:**

Hermetically sealed case

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

60.0 breakdown voltage, collector-to-base, emitter open and 40.0 breakdown voltage, collector-to-emitter, base open and 6.0 breakdown

voltage, emitter-to-base, collector open

### **Current Rating Per Characteristic:**

200.00 milliamperes source cutoff current

# **Power Rating Per Characteristic:**

225.0 milliwatts small-signal input power, common-collector

# Maximum Operating Tempurature Per Measurement Point:

165.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Terminal Type And Quantity:**

3 uninsulated wire lead

# Shelf Life:

N/a

#### Unit Of Measure:

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#### **Demilitarization:**

No

#### Fiig:

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